



DMTH4002SCTBQ

40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET TO263AB

Product Summary

| BV _{DSS} | Rds(on) Max | I _D Tc = +25°С |
|-------------------|---------------------------|------------------------------|
| 40V | $3m\Omega @ V_{GS} = 10V$ | 192A |

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

Features

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Low R_{DS(ON)}—Minimizes Power Losses
- Low Q_g—Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH4002SCTBQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

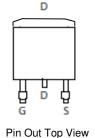
https://www.diodes.com/guality/product-definitions/

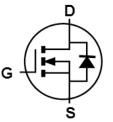
Mechanical Data

- Case: TO263AB
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 1.7 grams (Approximate)



Top View





Internal Schematic

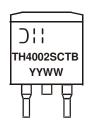
Ordering Information (Note 4)

| Part Number | Case | Packaging |
|------------------|-----------------|-----------------|
| DMTH4002SCTBQ-13 | TO263AB (D2PAK) | 800/Tape & Reel |

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2), & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



TH4002SCTB = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 20 = 2020) WW = Week (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|---|----------------------------------|-----------------|-------|----|
| Drain-Source Voltage | | VDSS | 40 | V |
| Gate-Source Voltage | | VGSS | ±20 | V |
| Continuous Drain Current (Note 6) | $T_{\rm C} = +25^{\circ}{\rm C}$ | l- | 192 | ٨ |
| Continuous Drain Current (Note 6) | Tc = +100°C | ID | 136 | А |
| Maximum Continuous Body Diode Forward Current (Note 6) | $T_{\rm C} = +25^{\circ}{\rm C}$ | ls | 100 | А |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | | ldм | 760 | А |
| Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%) | | lsм | 760 | А |
| Avalanche Current, L = 3mH | | I _{AS} | 19.2 | А |
| Avalanche Energy, L = 3mH | | Eas | 551.8 | mJ |

Thermal Characteristics

| Characteristic | | Symbol | Value | Unit |
|--|----------------------------------|-----------------------------------|-------------|------|
| Total Power Dissipation (Note 5) | TA = +25°C | PD | 6 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | | Reja | 25 | °C/W |
| Total Power Dissipation (Note 6) | $T_{\rm C} = +25^{\circ}{\rm C}$ | PD | 166.7 | W |
| Thermal Resistance, Junction to Case (Note 6) | | Rejc | 0.9 | °C/W |
| Operating and Storage Temperature Range | | T _J , T _{STG} | -55 to +175 | °C |

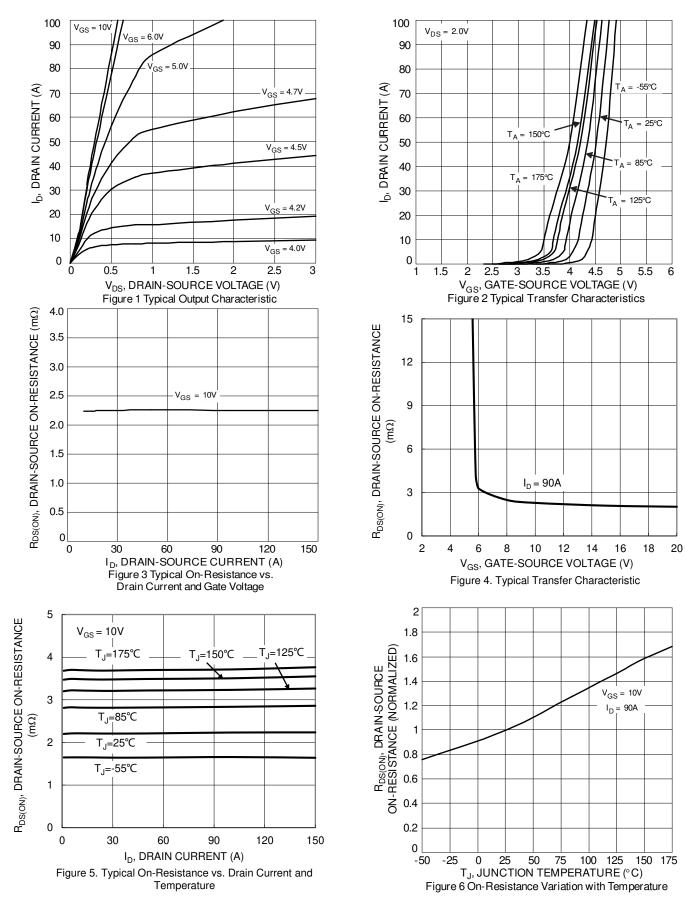
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|-----------------------------------|--------------------|-----|-------|------|------|--|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | ÷ | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 40 | — | — | V | $V_{GS} = 0V, I_D = 1mA$ | |
| Zero Gate Voltage Drain Current | IDSS | _ | — | 1 | μΑ | $V_{DS} = 32V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | — | - | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | VGS(TH) | 2 | - | 4 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | RDS(ON) | _ | 2.22 | 3 | mΩ | $V_{GS} = 10V, I_{D} = 90A$ | |
| Diode Forward Voltage | Vsd | — | 0.8 | 1.2 | V | $V_{GS} = 0V, I_{S} = 20A$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | Ciss | — | 7180 | — | | $V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz | |
| Output Capacitance | Coss | — | 1698 | — | pF | | |
| Reverse Transfer Capacitance | Crss | _ | 17 | _ | | | |
| Gate Resistance | Rg | _ | 1.04 | — | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$ | |
| Total Gate Charge | Qg | _ | 77.5 | _ | | $\label{eq:VDD} \begin{array}{l} V_{DD} = 20V, \ I_D = 90A, \\ V_{GS} = 10V \end{array}$ | |
| Gate-Source Charge | Qgs | _ | 23.6 | _ | nC | | |
| Gate-Drain Charge | Q _{gd} | _ | 13.6 | _ | | | |
| Turn-On Delay Time | t _{D(ON)} | | 16.8 | _ | | $\label{eq:VDD} \begin{split} V_{DD} &= 20V, V_{GS} = 10V, \\ I_D &= 90A, R_G = 3.5\Omega \end{split}$ | |
| Turn-On Rise Time | tR | | 8.0 | _ | | | |
| Turn-Off Delay Time | tD(OFF) | _ | 35.8 | _ | ns | | |
| Turn-Off Fall Time | tF | | 11.6 | _ | | | |
| Reverse Recovery Time | t _{RR} | _ | 46.36 | _ | ns | L 154 di/dt 1004/up | |
| Reverse Recovery Charge | Q _{RR} | _ | 56.11 | — | nC | - I _F = 15A, di/dt = 100A/μs | |

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

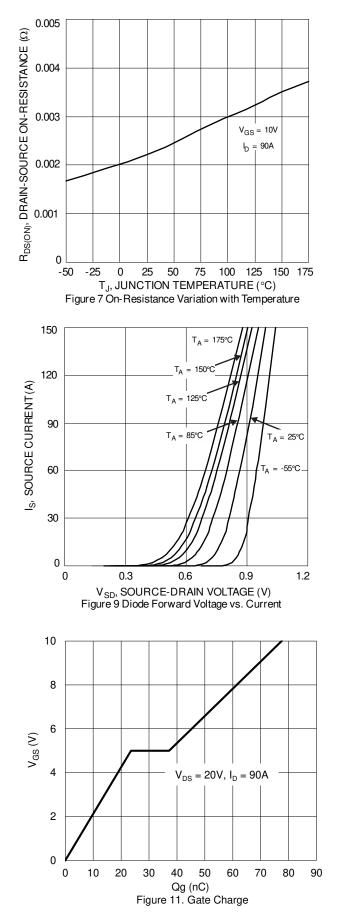


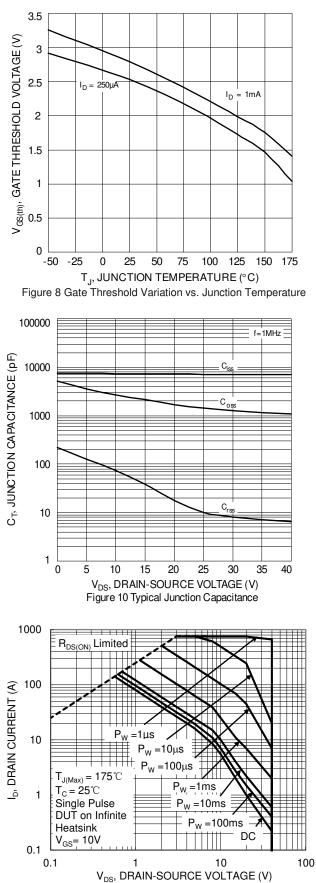
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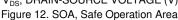




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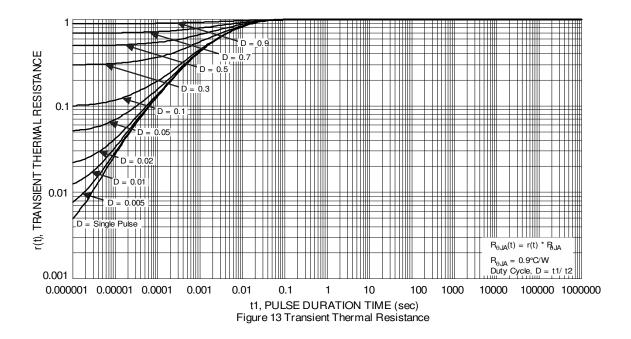






DMTH4002SCTBQ Document number: DS40950 Rev. 3 - 2

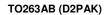


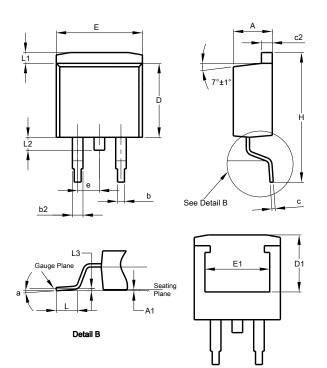




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



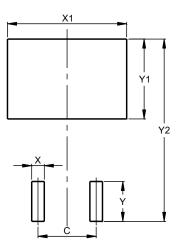


| TO263AB (D2PAK) | | | | | |
|----------------------|-------|----------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 4.07 | 4.82 | _ | | |
| A1 | 0.00 | 0.25 | — | | |
| b | 0.51 | 0.99 | — | | |
| b2 | 1.15 | 1.77 | _ | | |
| С | 0.356 | 0.73 | _ | | |
| c2 | 1.143 | 1.65 | _ | | |
| D | 8.39 | 9.65 | — | | |
| D1 | 6.55 | 6.95 | | | |
| е | | 2.54 TYP | | | |
| E | 9.66 | 10.66 | _ | | |
| E1 | 6.23 | 8.23 | _ | | |
| Н | 14.61 | 15.87 | _ | | |
| L | 1.78 | 2.79 | _ | | |
| L1 | _ | 1.67 | _ | | |
| L2 | _ | 1.77 | _ | | |
| L3 | — | _ | 0.254 | | |
| а | 0° | 8° | _ | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO263AB (D2PAK)



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 5.08 |
| Х | 1.10 |
| X1 | 10.41 |
| Y | 3.50 |
| Y1 | 7.01 |
| Y2 | 15.99 |



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